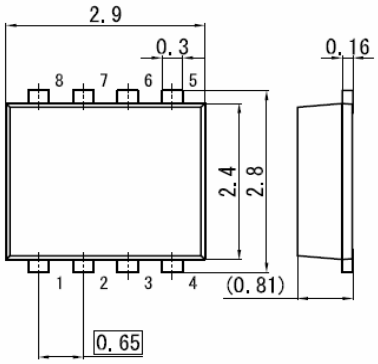
MTMC8E2A0LBF

Dual N-channel MOSFET

For lithium-ion secondary battery protection circuit

Unit: mm



1. Source(FET1) 5. Darin(FET1,2)
2. Gate(FET1) 6. Darin(FET1,2)
3. Source(FET2) 7. Darin(FET1,2)
4. Gate(FET2) 8. Darin(FET1,2)

Panasonic	WMini8-F1
JEITA	SC-115
Code	-

■ Features

- Low drain-source ON resistance:RDS(on)typ. = 15 mΩ (VGS = 4.5 V)
- Built-in gate resistor
- Halogen-free / RoHS compliant
  (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)

■ Marking Symbol: 4B

■ Packaging

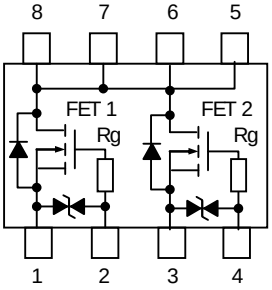
MTMC8E2A0LBF Embossed type (Thermo-compression sealing):
3 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 25 °C

Parameter		Symbol	Rating	Unit
FET1 FET2	Drain-source Voltage	VDS	20	V
	Gate-source Voltage	VGS	±12	V
	Drain Current	ID	7.0	A
	Peak Drain Current	IDp	42	A
Overall	Total Power Dissipation	PD1 *1	1.0	W
		PD2 *1,*2	1.2	
		PD3 *3	0.4	
	Channel Temperature Range	Tch	150	°C
	Storage Temperature	Tstg	-55 to +150	°C

Note: *1 Glass epoxy board: 25.4 mm × 25.4 mm × 0.8 mm Copper foil
of the drain portion should have a area of 300 mm^2 or more
PD absolute maximum rating Non-heat sink: 400 mW
*2 t = 10 s
*3 Non-heat sink

Internal Connection



Pin Name

1. Source(FET1) 5. Darin(FET1,2)
2. Gate(FET1) 6. Darin(FET1,2)
3. Source(FET2) 7. Darin(FET1,2)
4. Gate(FET2) 8. Darin(FET1,2)

Resistance Value	Rg	1	kΩ

■ Electrical Characteristics Ta = 25 °C ± 3 °C

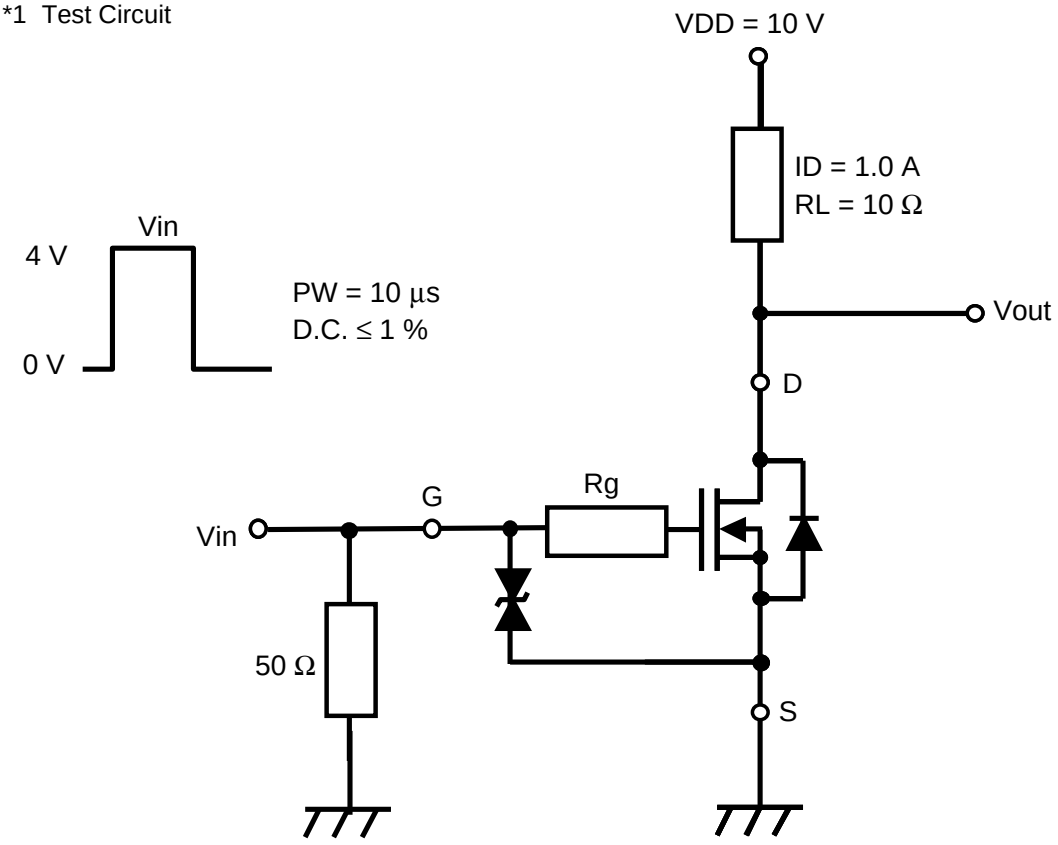
FET1,FET2

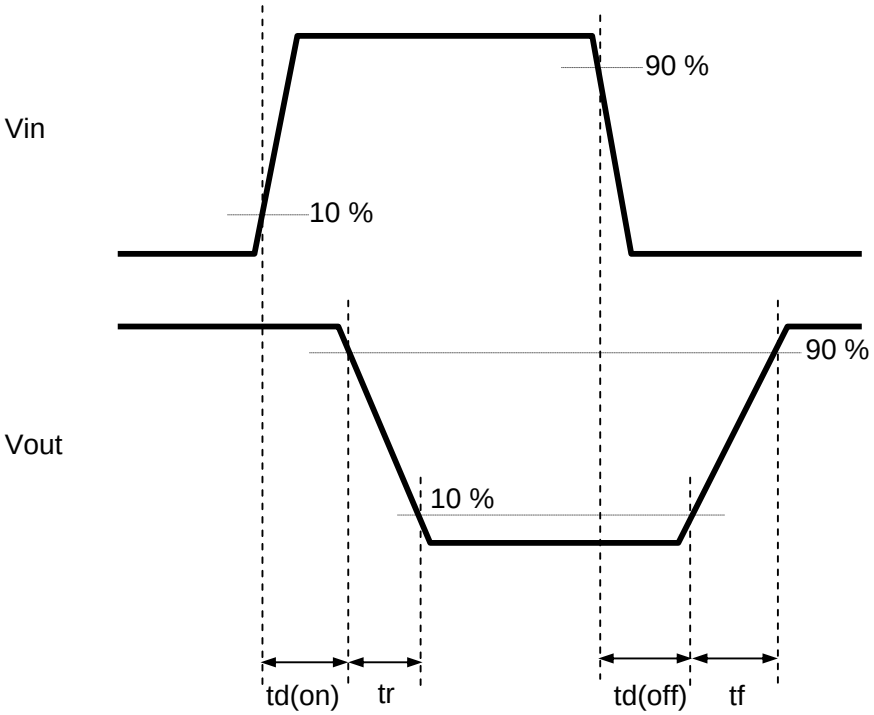
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Drain-source Breakdown Voltage	VDSS	ID = 1.0 mA, VGS = 0 V	20			V
Zero Gate Voltage Drain Current	IDSS	VDS = 20 V, VGS = 0 V			1.0	μA
Gate-source Leakage Current	IGSS	VGS = ±8.0 V, VDS = 0 V			±10	μA
Gate-source Threshold Voltage	Vth	ID = 1.0 mA, VDS = 10 V	0.40	0.85	1.30	V
Drain-source On-state Resistance	RDS(on)1	ID = 2.0 A, VGS = 4.5 V		15	21	mΩ
	RDS(on)2	ID = 2.0 A, VGS = 3.7 V		18	25	
	RDS(on)3	ID = 2.0 A, VGS = 2.5 V		22	33	
Forward transfer admittance	|Yfs|	ID = 1.0 A, VDS = -10 V	3.0			S
Input Capacitance	Ciss	VDS = 10 V, VGS = 0 V, f = 1 MHz		1 450		pF
Output Capacitance	Coss			100		
Reverse Transfer Capacitance	Crss			90		
Turn-on Delay Time *1	td(on)	VDD = 10 V, VGS = 0 to 4 V, ID = 1.0 A		0.33		μs
Rise Time *1	tr			0.70		
Turn-off Delay Time *1	td(off)	VDD = 10 V, VGS = 4 to 0 V, ID = 1.0 A		4.0		μs
Fall Time *1	tf			2.0		

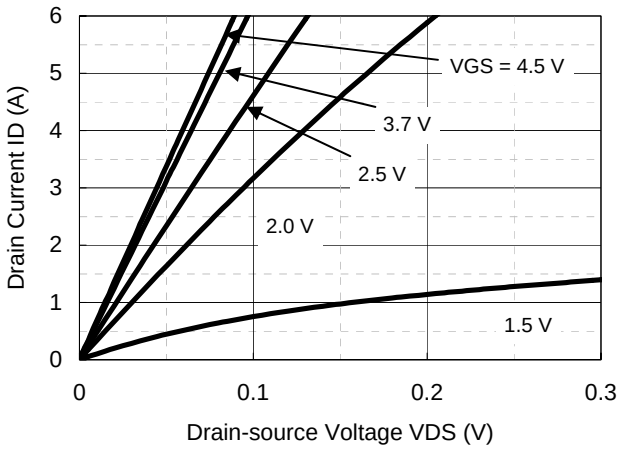
Note: Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

*1 See Test Circuit.

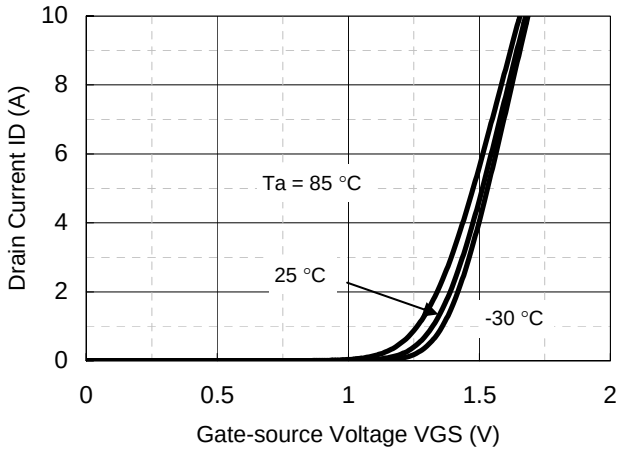
*1 Test Circuit



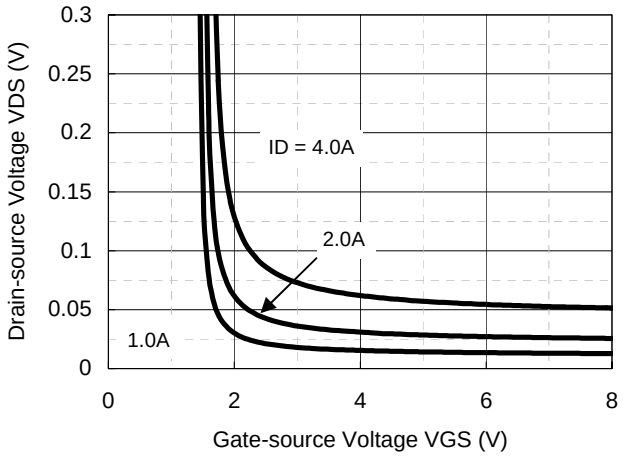




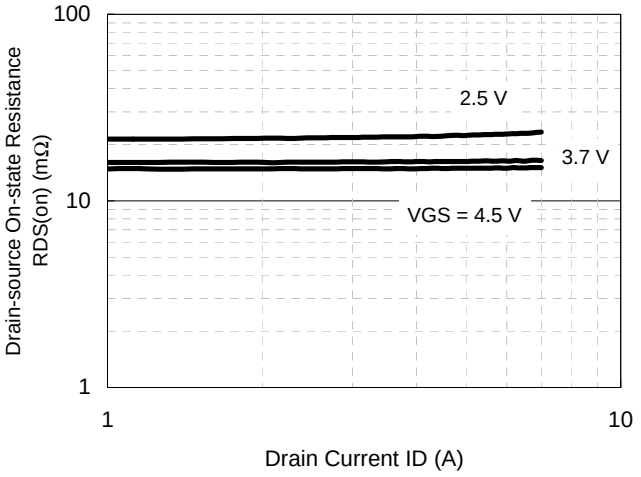
ID - VDS



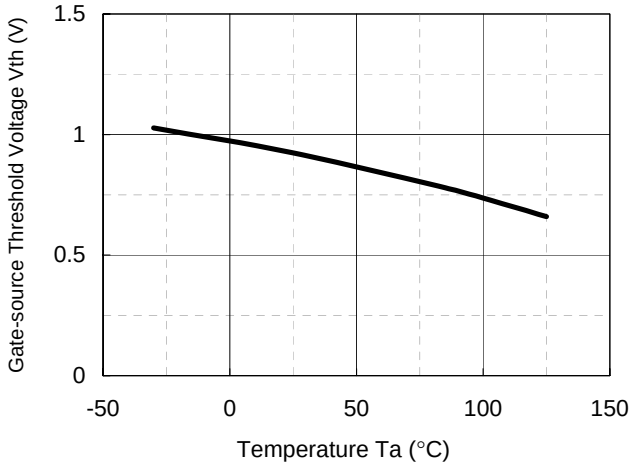
ID - VGS



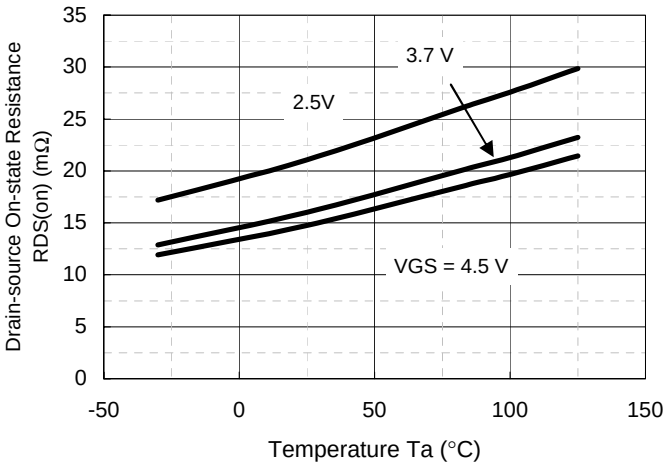
VDS - VGS



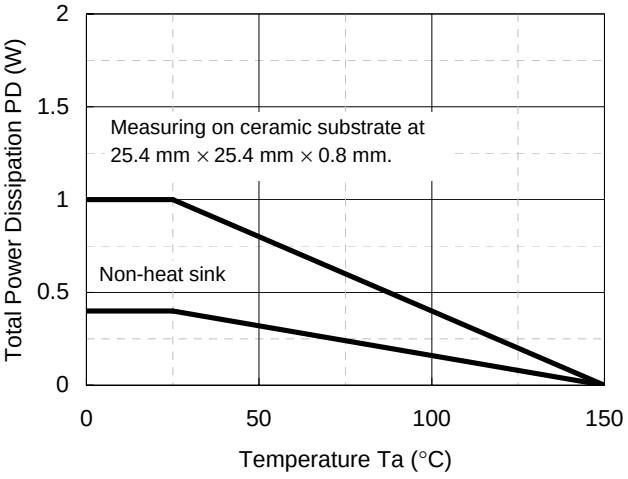
RDS(on) - ID



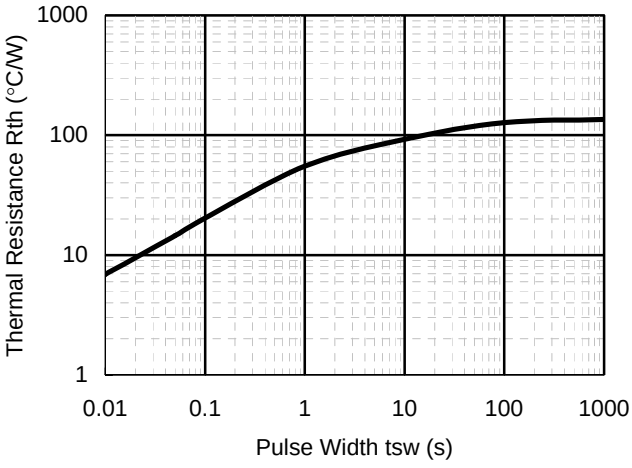
Vth - Ta



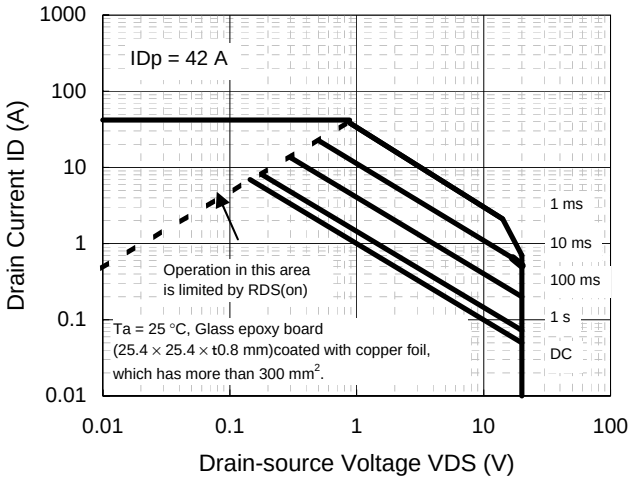
RDS(on) - Ta



PD - Ta



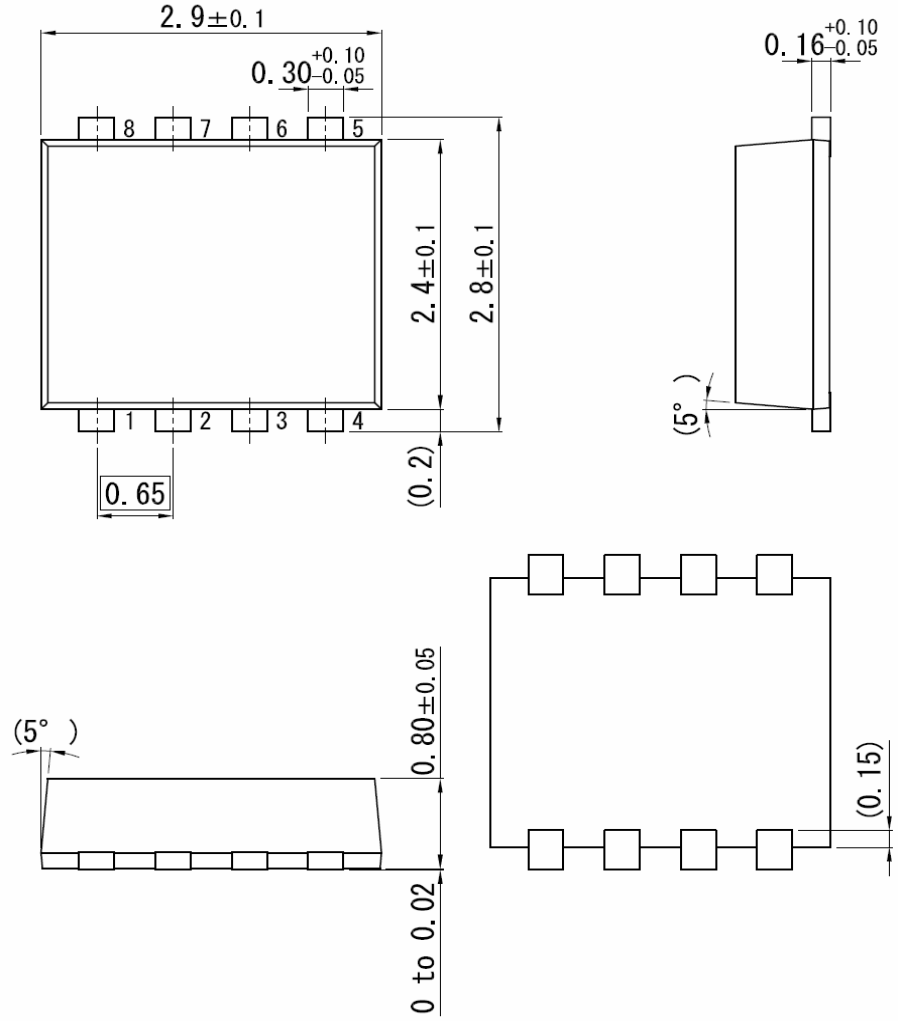
Rth -tsw



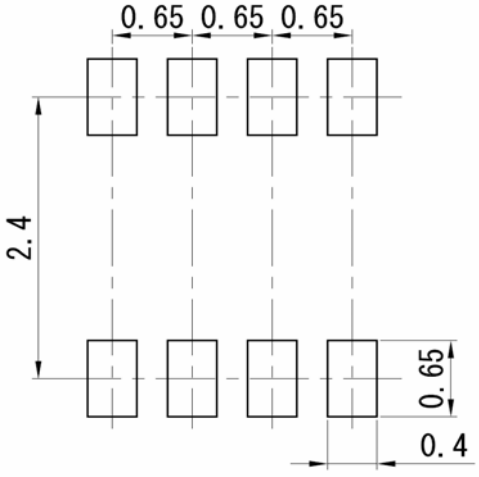
Safe Operating Area

WMini8-F1

Unit: mm



■ Land Pattern (Reference) (Unit: mm)



Request for your special attention and precautions in using the technical information and semiconductors described in this book

(1) If any of the products or technical information described in this book is to be exported or provided to non-residents, the laws and regulations of the exporting country, especially, those with regard to security export control, must be observed.

(2) The technical information described in this book is intended only to show the main characteristics and application circuit examples of the products. No license is granted in and to any intellectual property right or other right owned by Panasonic Corporation or any other company. Therefore, no responsibility is assumed by our company as to the infringement upon any such right owned by any other company which may arise as a result of the use of technical information described in this book.

(3) The products described in this book are intended to be used for general applications (such as office equipment, communications equipment, measuring instruments and household appliances), or for specific applications as expressly stated in this book.
Consult our sales staff in advance for information on the following applications:
- Special applications (such as for airplanes, aerospace, automotive equipment, traffic signaling equipment, combustion equipment, life support systems and safety devices) in which exceptional quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or harm the human body.

It is to be understood that our company shall not be held responsible for any damage incurred as a result of or in connection with your using the products described in this book for any special application, unless our company agrees to your using the products in this book for any special application.

(4) The products and product specifications described in this book are subject to change without notice for modification and/or improvement. At the final stage of your design, purchasing, or use of the products, therefore, ask for the most up-to-date Product Standards in advance to make sure that the latest specifications satisfy your requirements.

(5) When designing your equipment, comply with the range of absolute maximum rating and the guaranteed operating conditions (operating power supply voltage and operating environment etc.). Especially, please be careful not to exceed the range of absolute maximum rating on the transient state, such as power-on, power-off and mode-switching. Otherwise, we will not be liable for any defect which may arise later in your equipment.
Even when the products are used within the guaranteed values, take into the consideration of incidence of break down and failure mode, possible to occur to semiconductor products. Measures on the systems such as redundant design, arresting the spread of fire or preventing glitch are recommended in order to prevent physical injury, fire, social damages, for example, by using the products.

(6) Comply with the instructions for use in order to prevent breakdown and characteristics change due to external factors (ESD, EOS, thermal stress and mechanical stress) at the time of handling, mounting or at customer's process. When using products for which damp-proof packing is required, satisfy the conditions, such as shelf life and the elapsed time since first opening the packages.

20100202

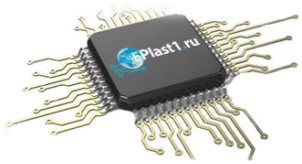
Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits,General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)
Факс: 8 (812) 320-02-42
Электронная почта: org@eplast1.ru
Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.